

# Quad Matched 741-Type Operational Amplifier

**OP11** 

### 1.0 SCOPE

This specification documents the detail requirements for space qualified die manufactured on Analog Devices, Inc.'s QML certified line per MIL-PRF-38534 class K except as modified herein.

The manufacturing flow described in the STANDARD DIE PRODUCTS PROGRAM brochure at <a href="http://www.analog.com/aerospace">http://www.analog.com/aerospace</a> is to be considered a part of this specification.

This data sheet specifically details the space grade version of this product. A more detailed operational description and a complete datasheet for commercial product grades can be found at www.analog.com/OP11

# **2.0** Part Number. The complete part number(s) of this specification follow:

Part Number Description

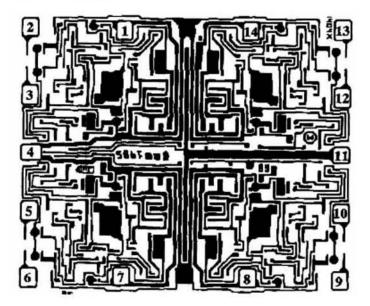
OP11-000C Quad Matched 741-Type Operational Amplifier

### 3.0 Die Information

### 3.1 Die Dimensions

Die Size	Die Thickness	Bond Pad Metalization	
72 mil x 86 mil	19 mil ± 2 mil	Al/Cu	

## 3.2 Die Picture



- 1. OUTPUT 1
- 2. -INPUT 1
- 3. +INPUT 1
- $4. +V_S$
- 5. +INPUT 2
- 6. -INPUT 2
- 7. OUTPUT 2
- 8. OUTPUT 3
- 9. -INPUT 3
- 10. +INPUT 3
- $11. -V_S$
- 12. +INPUT 4
- 13. -INPUT 4
- **14. OUTPUT 4**

## 3.3 Absolute Maximum Ratings 1/

Positive Supply Voltage (+V <sub>S</sub> )	+22V dc
Negative Supply Voltage (-V <sub>S</sub> )	-22V dc
Differential Input Voltage	±30V dc
Input Voltage (V <sub>IN</sub> )	Supply Voltage
Output Short Circuit Duration	Continuous
Storage Temperature Range	-65°C to +150°C
Ambient Operational Temperature Range	-55°C to +125°C

## Absolute Maximum Ratings Notes:

Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

## 4.0 Die Qualification

In accordance with class-K version of MIL-PRF-38534, Appendix C, Table C-II, except as modified herein.

- (a) Qual Sample Size and Qual Acceptance Criteria 10/0
- (b) Qual Sample Package DIP
- (c) Pre-screen test post assembly required prior to die qualification, to remove all assembly related rejects.

Table I - Dice Electrical Characteristics					
Parameter	Symbol	Conditions <u>1/</u>	Limit Min	Limit Max	Units
Input Offset Voltage	Vos	$R_S = 50\Omega$ , $10k\Omega$		±0.5	mV
Input Offset Current	Ios			±20	nA
Input Bias Current	$I_{\mathrm{IB}}$			±300	nA
Input Voltage Range	IVR		±12		V
Common Mode Rejection Ratio	CMRR	$V_{CM} = IVR$ $R_S = 50\Omega$ and $10k\Omega$	100		dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5V, \pm 15V$ $R_S = 50\Omega \text{ and } 10k\Omega,$		32	μV/V
Large Signal Voltage Gain	$A_{VOL}$	$V_{OUT} = \pm 10V, R_L = 2k\Omega$	100		V/mV
Output Voltage Swing	$V_{OUT}$	$R_L = 2k\Omega$	±11		V
Supply Current (All Four Amplifiers)	$I_{SY}$	$V_{O} = 0V$		6	mA

#### Table I Notes:

$$1/$$
  $\pm V_S = \pm 15V$ ,  $R_S = 50\Omega$ ,  $T_A = +25$ °C, and  $V_{CM} = 0V$ , unless otherwise specified.

Table II - Electrical Characteristics for Qual Samples						
Parameter	Symbol	Conditions <u>1/</u>	Sub- groups	Limit Min	Limit Max	Units
Input Offset Voltage	Vos	$R_S = 50\Omega$ , $10k\Omega$	1 2, 3		±0.5 ±1.0	mV
Input Offset Current	Ios		1 2, 3		±20 ±40	nA
Input Bias Current	$I_{\mathrm{IB}}$		1 2, 3		±300 ±375	nA
Input Voltage Range	IVR		1, 2, 3	±12		V
Common Mode Rejection Ratio	CMRR	$R_S = 50\Omega$ and $10k\Omega$ , $V_{CM} = IVR$	1, 2, 3	100		dB
Power Supply Rejection Ratio	PSRR	$V_S = \pm 5V, \ \pm 15V$ $R_S = 50\Omega$ and $10k\Omega$	1, 2, 3		32	μV/V
Large Signal Voltage Gain	A <sub>VOL</sub>	$V_{OUT} = \pm 10V, R_L = 2k\Omega$	4 5, 6	100 50		V/mV
Output Voltage Swing	V <sub>OUT</sub>	$R_L = 2k\Omega$	4, 5, 6	±11		V
Supply Current (All Four Amplifiers)	I <sub>SY</sub>	$V_O = 0V$	1 2, 3		6 6.7	mA

# Table II Notes:

1/2  $\pm V_S = \pm 15V$ ,  $R_S = 50\Omega$ , and  $V_{CM} = 0V$ , unless otherwise specified.

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Table III - Life Test Endpoint and Delta Parameter (Product is tested in accordance with Table II with the following exceptions) Life Post Burn In Limit Post Life Test Limit Sub-Symbol Units Parameter Test groups Min Min Max Max Delta  $\pm 0.7$  $\pm 0.9$  $\pm 0.2$ 1 Input Offset Voltage Vos mV 2, 3 ±1.4  $\pm 350$  $\pm 400$ 1  $\pm 50$ Input Bias Current  $I_{IB}$ nΑ 2, 3 ±475  $\pm 25$  $\pm 30$ 1 Input Offset Current  $I_{OS}$ nA 2, 3  $\pm 50$ 

### 5.0 Life Test/Burn-In Information

- **5.1** HTRB is not applicable for this drawing.
- **5.2** Burn-in is per MIL-STD-883 Method 1015 test condition B or C.
- **5.3** Steady state life test is per MIL-STD-883 Method 1005.

Rev	Description of Change	Date
Α	Initiate	25-Sep-071
В	Update web address	Jan. 25, 2002
С	Update web address	Aug. 5, 2003